

### Vishay General Semiconductor

### **Dual High Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.57 \text{ V}$  at  $I_F = 2.5 \text{ A}$ 





PRIMARY CHARACTERISTICS			
I <sub>F(AV)</sub>	2 x 5 A		
$V_{RRM}$	170 V		
I <sub>FSM</sub>	80 A		
$V_F$ at $I_F = 5.0 A$	0.65 V		
T <sub>J</sub> max.	175 °C		
Package	TO-263AB		
Diode variations	Common cathode		

#### **FEATURES**

• Trench MOS Schottky technology

· High efficiency operation



· Low forward voltage drop, low power losses

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(e3)

 Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C

RoHS COMPLIANT

 Material categorization: For definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

#### **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

#### **MECHANICAL DATA**

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per

 $\ensuremath{\mathsf{J-STD}}\xspace-002$  and  $\ensuremath{\mathsf{JESD}}\xspace 22\xspace-B102$ 

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	VB10170C	UNIT
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	170	V
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	10	^
	per diode		5	Α
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	80	А
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +175	°C



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.74	-	V	
	I <sub>F</sub> = 5.0 A			0.84	1.03		
	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 125 °C		0.57	-		
	I <sub>F</sub> = 5.0 A			0.65	0.74		
Reverse current per diode	V <sub>R</sub> = 136 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	0.3	-	μA	
		T <sub>A</sub> = 125 °C		0.9	-	mA	
	V <sub>R</sub> = 170 V	T <sub>A</sub> = 25 °C		-	90	μA	
		T <sub>A</sub> = 125 °C		1.3	10	mA	

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	VB10170C	UNIT
Typical thermal resistance	per diode	$R_{ hetaJC}$	3.0	°C/W
	per device		1.7	- C/VV

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VB10170C-E3/4W	1.38	4W	50/tube	Tube	
TO-263AB	VB10170C-E3/8W	1.38	8W	800/reel	Tape and reel	

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

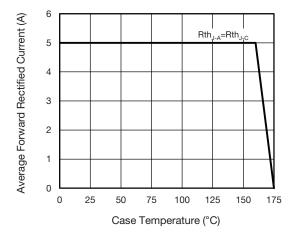


Fig. 1 - Maximum Forward Current Derating Curve

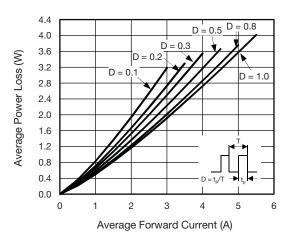


Fig. 2 - Forward Power Loss Characteristics Per Diode



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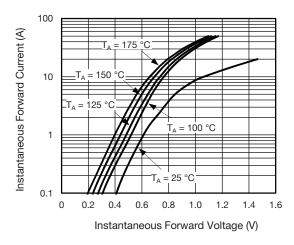


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

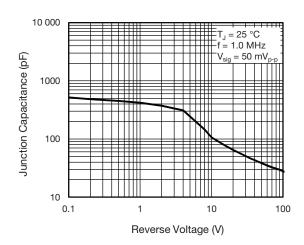


Fig. 5 - Typical Junction Capacitance Per Diode

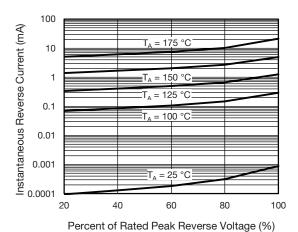


Fig. 4 - Typical Reverse Characteristics Per Diode

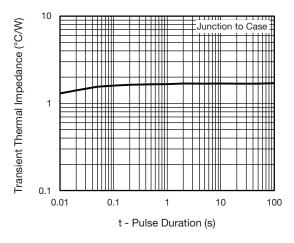


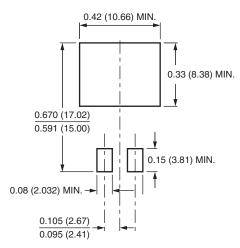
Fig. 6 - Typical Transient Thermal Impedance Per Diode

### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-263AB

#### 0.411 (10.45) 0.190 (4.83) 0.380 (9.65) 0.160 (4.06) 0.055 (1.40) 0.045 (1.14) 0.245 (6.22) MIN 0.055 (1.40) 0.360 (9.14) 0.047 (1.19) 0.320 (8.13) 0.624 (15.85) K 2 0.591 (15.00) 0 to 0.01 (0 to 0.254) 0.110 (2.79) 0.090 (2.29) 0.037 (0.940) 0.021 (0.53) 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56) 0.095 (2.41) 0.205 (5.20) 0.110 (2.79) 0.195 (4.95)

#### **Mounting Pad Layout**





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